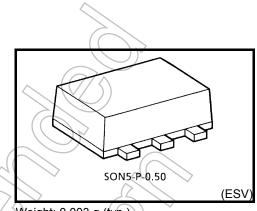
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SH125FE

Bus Buffer with 3-STATE Output

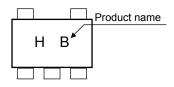
#### **Features**

- High speed:  $t_{pd}$  = 3.8 ns (typ.) at  $V_{CC}$  = 5V, 15pF
- Low power dissipation: I<sub>CC</sub> = 2μA (max) at Ta = 25°C
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- 5.5-V tolerant input.
- Wide operating voltage range: V<sub>CC</sub> = 2 to 5.5 V

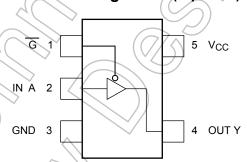


Weight: 0.003 g (typ.)

#### Marking



### Pin Assignment (top view)



### Absolute Maximum Ratings (Ta = 25°C)

| Characteristics                    | Symbol              | Rating                        | Unit |
|------------------------------------|---------------------|-------------------------------|------|
| Supply voltage range               | V <sub>CC</sub>     | -0.5 to 7                     | V    |
| DC input voltage                   | VIN                 | -0.5 to 7                     | V    |
| DC output voltage                  | V <sub>OUT</sub>    | −0.5 to V <sub>CC</sub> + 0.5 | V    |
| Input diode current                | ljk <sub>&gt;</sub> | -20                           | mA   |
| Output diode current               | Tok                 | ±20 (Note1)                   | mA   |
| DC output current                  | Tout                | ±25                           | mA   |
| DC V <sub>CC</sub> /ground current | Icc                 | ±50                           | mA   |
| Power dissipation                  | PD                  | 150                           | mW   |
| Storage temperature                | T <sub>stg</sub>    | -65 to 150                    | °C   |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Vout < GND, Vout > Vcc

Start of commercial production 2004-05

# IEC Logic Symbol



# Truth Table

| G | Α | Υ |
|---|---|---|
| Н | Х | Z |
| L | L | L |
| L | Н | Н |

# **Operating Ranges**

| Characteristics          | Symbol           | Rating                                       | Unit   |
|--------------------------|------------------|--|--------|
| Supply voltage           | V <sub>CC</sub>  | 2 to 5.5                                     | V      |
| Input voltage            | V <sub>IN</sub>  | 0 to 5.5                                     | V      |
| Output voltage           | V <sub>OUT</sub> | 0 to V <sub>C</sub> C                        | V      |
| Operating temperature    | T <sub>opr</sub> | -40 to 85                                    | °C     |
| Input rice and fall time | dt/dv            | 0 to 100 ( V <sub>CC</sub> = 3.3 V ± 0.3 V ) | ns/V   |
| Input rise and fall time | di/dv            | 0 to 20 ( V <sub>CC</sub> = 5 V ± 0.5 V )    | IIS/V) |

### **Electrical Characteristics**

### **DC Characteristics**

| Characteristics                  | Symbol          | Took Condition  |                          |                     | Ta = 25°C             |            |                          | Ta = -40 to 85°C         |   | Unit  |
|----------------------------------|-----------------|---|--------------------------|---------------------|-----------------------|------------|--------------------------|--------------------------|---|-------|
| Characteristics Symbo            |                 | Test Condition  |                          | V <sub>CC</sub> (V) | Min                   | Тур.       | Max                      | Min                      | Max   | Offic |
| High-level input                 |                 |   |                          | 2.0                 | 1.5                   | - <        | _                        | 1.5                      | _   |       |
| voltage VIH                      |                 | _   |                          | 3.0 to 5.5          | V <sub>CC</sub> × 0.7 | _          | M                        | V <sub>CC</sub><br>× 0.7 |   | V     |
| Low-level input                  |                 |   |                          | 2.0                 | _                     | _ (        | 0.5                      | //_                      | 0.5   | ٧     |
| voltage                          | V <sub>IL</sub> | -   | _                        |                     | 1                     | (()        | V <sub>CC</sub><br>× 0.3 | _                        | $\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$ |       |
|                                  |                 |   | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9                   | 2.0        |                          | 1.9                      | _   | V     |
|                                  | V <sub>ОН</sub> | V <sub>IN</sub> = V <sub>IH</sub><br>or V <sub>IL</sub> |                          | 3.0                 | 2.9                   | 3.0        | _                        | 2.9                      |   |       |
| High-level output voltage        |                 |   |                          | 4.5                 | 4.4                   | 4.5        |                          | 4.4                      |   |       |
|                                  |                 |   | $I_{OH} = -4 \text{ mA}$ | 3.0                 | 2.58                  | $\searrow$ |                          | 2.48                     | $\rightarrow$   |       |
|                                  |                 |   | $I_{OH} = -8 \text{ mA}$ | 4.5                 | 3.94                  | _          | {_                       | 3.80                     | . —   |       |
|                                  | V <sub>OL</sub> | $V_{IN} = V_{IL}$                                       | I <sub>OL</sub> = 50 μA  | 2.0                 | )                     | 0 🔷        | 0.1                      | 2)                       | 0.1   |       |
| 1 1 4                            |                 |   |                          | 3.0                 |                       | 0          | 0.1                      | 94//                     | 0.1   |       |
| Low-level output<br>voltage      |                 |   |                          | 4.5                 | _                     | 0          | 0.1                      | > _                      | 0.1   |       |
|                                  |                 |   | I <sub>OL</sub> = 4 mA   | 3.0                 | _                     |            | 0.36                     | _                        | 0.44  |       |
|                                  |                 |   | $I_{OL} = 8 \text{ mA}$  | 4.5                 | _                     | (7)        | 0.36                     | _                        | 0.44  |       |
| 3-state output off-state current | loz             | $V_{IN} = V_{IH}$ or $V_{II}$                           |                          | 5.5                 |                       |            | ±0.25                    | _                        | ±2.5  | μΑ    |
| Input leakage current            | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or                              | GND                      | 0 to 5.5            | _                     | ) )—       | ±0.1                     | _                        | ±1.0  | μА    |
| Quiescent supply current         | Icc             | V <sub>IN</sub> = V <sub>CC</sub> or G                  | BND                      | 5.5                 |                       | /_         | 2.0                      | _                        | 20.0  | μА    |

### AC Characteristics (unless otherwise specified, input: $t_r = t_f = 3$ ns)

| Characteristics Symbol        |                                      | Test<br>Circuit |   | Test Condition      |                     | Ta = 25°C |       |      | Ta = -40 to<br>85°C |                 | Unit |
|-------------------------------|--------------------------------------|-----------------|---|---------------------|---------------------|-----------|-------|------|---------------------|-----------------|------|
|                               |                                      | Ollicuit        |   | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min       | Тур.  | Max  | Min                 | Max             |      |
|                               |                                      |                 |   | 3.3 ± 0.3           | 15                  | _         | 5.6   | 8.0  | 1.0                 | 9.5             |      |
| Propagation delay             | $t_{pLH}$                            | _               | _ | 3.3 ± 0.3           | 50                  | _         | 8.1 < | 11.5 | 1.0                 | 13.0            | ns   |
| time                          | $t_{pHL}$                            |                 |   | 5.0 ± 0.5           | 15                  | _         | 3.8   | 5.5  | 1.0                 | 6.5             |      |
|                               |                                      |                 |   | 3.0 ± 0.3           | 50                  | _         | 5.3   | 7.5  | 1.0                 | 8.5             |      |
|                               |                                      |                 |   | 3.3 ± 0.3           | 15                  |           | 5,4   | 8.0  | 1.0                 | 9.5             |      |
| 3-state output                | t <sub>pZL</sub><br>t <sub>pZH</sub> | _               | _ | 3.3 ± 0.3           | 50                  | 4         | 7.9   | 11.5 | 1.0                 | 13.0            | - ns |
| enable time                   |                                      |                 |   | 5.0 ± 0.5           | 15                  | -         | 3.6   | 5.1  | 1.0                 | 6.0             |      |
|                               |                                      |                 |   | 3.0 ± 0.3           | 50                  | -(        | 5.1   | 7.1  | 1.0                 | 8.0             |      |
| 3-state output                | t <sub>pLZ</sub>                     |                 |   | $3.3\pm0.3$         | 50                  |           | 9.5   | 13.2 | 1.0                 | 15.0            | ns   |
| disable time                  | $t_{pHZ}$                            | _   _           | _ | 5.0 ± 0.5           | 50                  | 1/ J      | 6.1   | 8.8  | <1.0                | 10.0            | 115  |
| Input capacitance             | C <sub>IN</sub>                      | _               |   | _                   | (                   | >_        | 4     | 10   |                     | <del>)</del> 10 | pF   |
| Output capacitance            | C <sub>OUT</sub>                     | _               |   | _                   |                     | )         | 6 🛇   | =    |                     | ) —             | pF   |
| Power dissipation capacitance | C <sub>PD</sub>                      | _               |   | 50                  | (Note2)             | _         | 14    | 7    | \$ <u></u>          | _               | pF   |

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

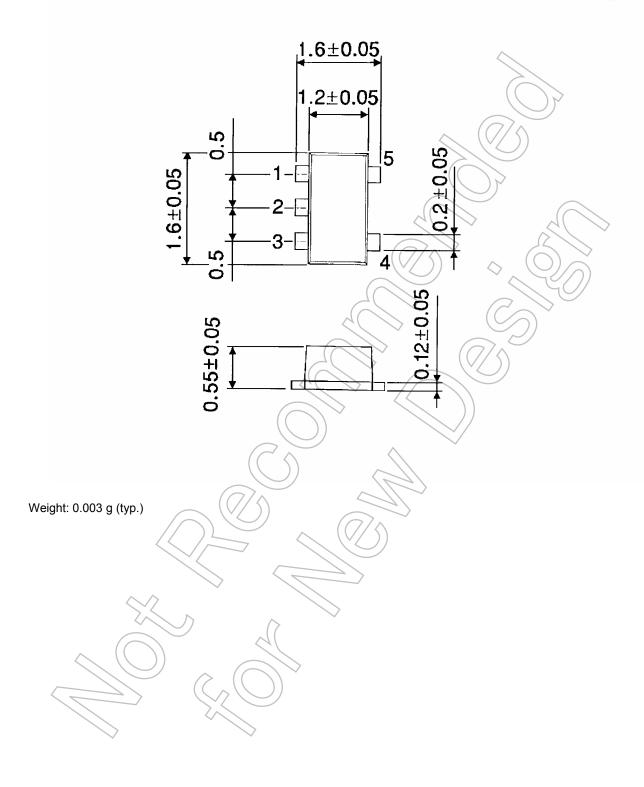
Average operating current can be obtained by the equation.



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### **Package Dimensions**

SON5-P-0.50 Unit: mm



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